

KNOX SEMICONDUCTOR, INC.

A unique manufacturing process allows Knox Semiconductor to supply a range of Low Voltage Diodes having Very Low Impedances at Low Current Levels. These remarkably sharp breaking diodes have the lowest values of impedance ever achieved at the 250 μ A level. These devices will find wide use in any application where low currents and low impedances are desired.

LOW LEVEL ZENER DIODES SHARP KNEE, LOW IMPEDANCE K511 - K681

TYPE NUMBER	NOMINAL ZENER VOLTAGE @ Iz = 250 μ A (Vdc)	DYNAMIC IMPEDANCE		REVERSE CURRENT @ 25° C	
		MAX Zz @ Iz = 250 μ A (OHMS)	MAX Zzk @ Iz = 1 mA (OHMS)	MAX Ir (μA)	Vr (Vdc)
K511	5.1	50	15	.05	2.5
K561	5.6	45	15	.05	3.5
K621	6.2	35	18	.05	5.6
K681	6.8	25	18	.05	6.4

Package Style DO-7
DC Power Dissipation 250 mW
Derate above 50° C 2 mW / °C
Forward Voltage Drop 1.3 Vdc
Operating Temperature (Topr) -65 to + 175° C
Storage Temperature (Tstg) -65 to + 200° C
Voltage Tolerance: Standard Device ±10%